

0.6 μ A Current Consumption Voltage Regulator

FEATURES

- Low Power Consumption at 0.6 μ A typical
- Operating Voltage Range 1.4 V – 6.0 V
- Output Voltage Range from 1.1 V to 5.0 V with 0.1 V increments
- Output Voltage Accuracy ± 0.02 V at $V_{OUT} < 2.0$ V, or $\pm 1\%$
- Temperature Stability ± 50 ppm/ $^{\circ}$ C
- Output Current up to 150 mA
- Dropout Voltage 500 mV @ 150 mA, $V_{OUT} = 3.0$ V
- Standby Current less than 0.01 μ A typical
- Load Capacitor Auto Discharge
- Current Limit and Short Circuit Protection
- Low ESR Ceramic Capacitor compatible
- Stable operations without load capacitor
- ON/OFF switch
- Operating Ambient Temperature - 40 + 85 $^{\circ}$ C
- Packages : SOT-25, SSOT-24, and USPN-4B02
- EU RoHS Compliant, Pb Free

APPLICATIONS

- Mobile phones
- Cameras, VCRs
- Various portable equipment

DESCRIPTION

The IXD1504 is a highly accurate CMOS voltage regulator with very low supply current of 0.6 μ A. It is able to provide very accurate output voltage even at load current as low as 1 μ A, which is ideally suited for the battery-powered applications. The usage of super small package USPN-4B02 (0.75 x 0.95 mm) and the advantage of capacitor-less stable operations contribute to the board space saving.

The IC consists of a reference voltage source, an error amplifier, a driver transistor, over-current protection circuit, and a phase compensation circuit.

Excellent internal phase compensation allows the IXD1504 operate either with a low ESR ceramic output capacitor C_L , or even without it.

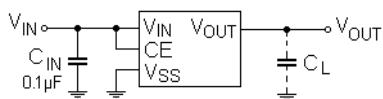
Output voltage is fixed internally by laser trimming technology and selectable in 0.1 V increments within the range from 1.1 V to 5.0 V.

The CE input allows set IXD1504 into standby mode reducing current consumption to less than 0.01 μ A.

If a C_L output capacitor is used, the internal switch discharges this capacitor in standby mode to return quickly V_{OUT} voltage to the V_{SS} level,

Regulator is available in SOT-25, SSOT-24, and USPN-4B02 packages.

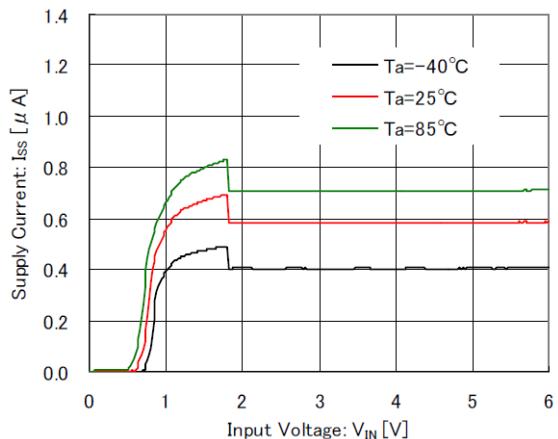
TYPICAL APPLICATION CIRCUIT



TYPICAL PERFORMANCE CHARACTERISTIC

Supply Current vs. Input Voltage

$C_{IN} = C_L = \text{open}, V_{CE} = V_{IN}, I_{OUT} = 0 \text{ mA},$



ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNITS	
Input Voltage		V _{IN}	-0.3 ~ +6.5	V	
Output Current		I _{OUT}	470 ¹⁾	mA	
Output Voltage		V _{OUT}	-0.3 ~ V _{IN} + 0.3 or +6.5 V ²⁾	V	
CE Input Voltage		V _{CE}	-0.3 ~ +6.5	V	
Power Dissipation ²⁾	SOT-25	P _D	250	mW	
			600 (PCB mounted)		
	SSOT-24		150		
			500 (PCB mounted)		
	USPN-4B02		100		
			550 (PCB mounted)		
Operating Temperature Range	T _{OPR}		-40 ~ +85	°C	
Storage Temperature Range	T _{STG}		-55 ~ +125	°C	

All voltages are in respect to V_{SS}1) I_{OUT} ≤ Pd / (V_{IN} · V_{OUT})2) The lowest value between V_{IN} + 0.3 and 6.5 V

3) This is a reference data taken by using the test board. Please refer to page 20 to 22 for details

ELECTRICAL OPERATING CHARACTERISTICS

Ta = 25 °C

PARAMETER	SYMBOL	CONDITIONS		MIN.	TYP.	MAX.	UNIT	CIRCUIT
Input Voltage	V _{IN}			1.4		6.0	V	①
Output Voltage ¹⁾	V _{OUT(E)}	V _{OUT(T)} ≥ 2 V ³⁾		V _{OUT(T)} × 0.99	V _{OUT(T)} *	V _{OUT(T)} × 1.01	V	①
		V _{OUT(T)} < 2 V ³⁾		V _{OUT(T)} × 0.02	V _{OUT(T)} *	V _{OUT(T)} + 0.02		
Maximum Output Current	I _{OUT_MAX}			150			mA	①
Load Regulation	ΔV _{OUT}	1 μA ≤ I _{OUT} ≤ 1 mA			3	16	mV	①
		1 mA ≤ I _{OUT} ≤ 150 mA			17	50		
Dropout Voltage ²⁾	V _{DIF1}	I _{OUT} = 50 mA		E-1 ³⁾			V	①
	V _{DIF2}	I _{OUT} = 150 mA		E-2 ³⁾				
Supply Current	I _{SS}	I _{OUT} = 0 mA	V _{OUT(T)} < 1.9 V		0.60	1.27	μA	②
			1.9 V ≤ V _{OUT(T)} < 4.0 V		0.65	1.50		
			V _{OUT(T)} ≥ 4.0 V		0.80	1.80		
Standby Current	I _{STB}	V _{CE} = 0 V			0.01	0.10	μA	②
Line Regulation	$\frac{\Delta V_{OUT}}{V_{OUT} * \Delta V_{IN}}$	I _{OUT} = 1 μA, V _{OUT(T)} + 0.5 V ≤ V _{IN} ≤ 6.0 V			0.01	0.13	%/V	①
		I _{OUT} = 1 mA, V _{OUT(T)} + 0.5 V ≤ V _{IN} ≤ 6.0 V, if V _{OUT(T)} ≥ 1.2 V, or 1.7 V ≤ V _{IN} ≤ 6.0 V			0.01	0.19		
Output Voltage Temperature Characteristics	$\frac{\Delta V_{OUT}}{V_{OUT} * \Delta T_{OPR}}$	I _{OUT} = 10 mA -40 °C ≤ T _{OPR} ≤ 85 °C			± 50		ppm/°C	①
Current Limit	I _{LIM}	V _{OUT} = V _{OUT(E)} × 0.95		150	270		mA	①
Short Current	I _{SHORT}	V _{OUT} = V _{SS}			80		mA	①
C _L Discharge Resistance	R _{DCH}	V _{CE} = 0 V, V _{OUT} = V _{OUT(T)}		280	450	640	Ω	①
CE "H" Level Voltage	V _{CEH}				0.91		V _{IN}	③
CE "L" Level Voltage	V _{CEL}					0.38	V	③
CE "H" Level Current	I _{CEH}	V _{CE} = V _{IN} = 6.0 V		-0.1		0.1	μA	③
CE "L" Level Current	I _{CEL}	V _{IN} = 6.0 V, V _{CE} = V _{SS}		-0.1		0.1	μA	③

NOTE:

Unless otherwise stated, V_{IN} = V_{CE} = V_{OUT(T)} + 1.0 V, if V_{OUT(T)} ≥ 2.5 V, or V_{IN} = V_{CE} = 3.5 V, I_{OUT} = 1 mA, C_{IN} = C_{LOAD} = open1) V_{OUT(T)} is Nominal output voltage and V_{OUT(E)} is Effective output voltage, (i.e. the output voltage when "V_{OUT(T)} + 1.0V" is provided at the V_{IN} pin, while maintaining a certain I_{OUT} value).2) V_{DIF} = {V_{IN}-V_{OUT}}, where V_{IN} is the input voltage when V_{OUT} = 0.98 V_{OUT(T)} appears, while input voltage gradually decreases

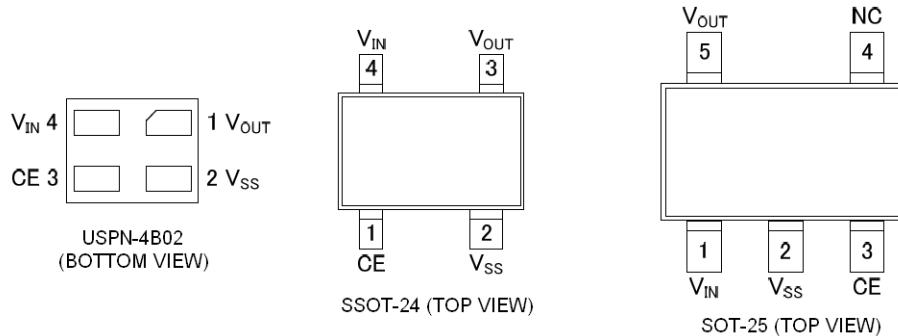
3) Refer to the Table "Voltage Chart. Dropout Voltage"

ELECTRICAL OPERATING CHARACTERISTICS (CONTINUED)

Voltage Chart

NOMINAL OUTPUT VOLTAGE $V_{OUT(T)}$, V	OUTPUT VOLTAGE, V		E-1		E-2	
			DROPOUT VOLTAGE, V			
	$V_{OUT(E)}$		Vdif1		Vdif2	
(V)	MIN.	MAX.	TYP.	MAX.	TYP.	MAX.
1.1	1.0800	1.1200	0.96	1.35	1.51	2.05
1.2	1.1800	1.2200	0.87	1.23	1.41	1.93
1.3	1.2800	1.3200	0.77	1.12	1.33	1.83
1.4	1.3800	1.4200	0.69	1.01	1.24	1.72
1.5	1.4800	1.5200	0.62	0.91	1.17	1.63
1.6	1.5800	1.6200	0.56	0.84	1.10	1.54
1.7	1.6800	1.7200	0.51	0.77	1.04	1.47
1.8	1.7800	1.8200	0.47	0.72	0.99	1.40
1.9	1.8800	1.9200	0.42	0.64	0.92	1.29
2.0	1.9800	2.0200	0.37	0.58	0.86	1.20
2.1	2.0790	2.1210		0.31	0.47	0.75
2.2	2.1780	2.2220	0.26		0.75	1.05
2.3	2.2770	2.3230	0.23	0.40	0.67	
2.4	2.3760	2.4240		0.20		0.60
2.5	2.4750	2.5250	0.17	0.34	0.82	
2.6	2.5740	2.6260		0.15		0.60
2.7	2.6730	2.7270	0.13	0.30	0.54	
2.8	2.7720	2.8280		0.11		0.54
2.9	2.8710	2.9290	0.17	0.26	0.67	
3.0	2.9700	3.0300		0.15		0.50
3.1	3.0690	3.1310	0.22	0.43	0.59	
3.2	3.1680	3.2320		0.13		0.38
3.3	3.2670	3.3330	0.19	0.35	0.47	
3.4	3.3660	3.4340		0.11		0.32
3.5	3.4650	3.5350	0.17	0.16		
3.6	3.5640	3.6360				
3.7	3.6630	3.7370	0.13	0.19		
3.8	3.7620	3.8380				
3.9	3.8610	3.9390	0.11	0.17		
4.0	3.9600	4.0400				
4.1	4.0590	4.1410	0.11	0.17		
4.2	4.1580	4.2420				
4.3	4.2570	4.3430	0.10	0.32		
4.4	4.3560	4.4440				
4.5	4.4550	4.5450	0.10	0.32		
4.6	4.5540	4.6460				
4.7	4.6530	4.7470	0.10	0.32		
4.8	4.7520	4.8480				
4.9	4.8510	4.9490	0.10	0.32		
5.0	4.9500	5.0500				

PIN CONFIGURATION

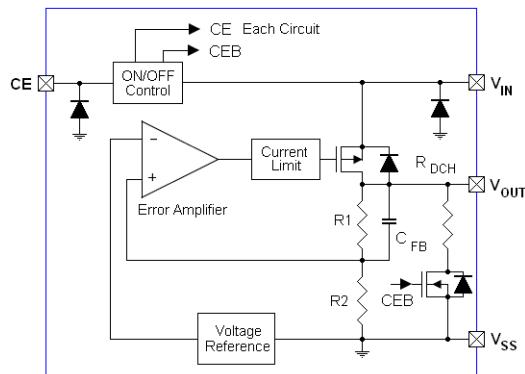


PIN ASSIGNMENT

PIN NUMBER			PIN NAME	FUNCTIONS
SOT-25	SSOT-24	USPN-4B02		
5	3	1	V _{OUT}	Output Voltage
2	2	2	V _{SS}	Ground
3	1	3	CE	ON/OFF Control LOW – Standby mode, HIGH – Active ¹⁾
1	4	4	V _{IN}	Power Input
4			NC	No Connection

1) CE input does not have pull-down resistor and should not be in OPEN state. Connect it to the defined voltage source.

BLOCK DIAGRAM



IXD1504A

Diodes inside the circuits are ESD protection diodes and parasitic diodes.

BASIC OPERATION

The Error Amplifier of the IXD1504 series monitors output voltage divided by internal resistors R1 & R2 and compares it with the internal Reference Voltage (see Block Diagram above). The output signal from error amplifier drives gate of the P-channel MOSFET, which is connected to the V_{OUT} pin and operates as a series voltage regulator.

The Current Limit/Short Protection circuits monitor level of the output current. The CE pin allows shutdown internal circuitry to minimize power consumption.

Current Limiter, Short-Circuit Protection

The IXD1504 series include a combination of a fixed current limiter circuit & a foldback circuit, which aid the operations of the current limiter and circuit protection. When the load current reaches the current limit level, the fixed current limiter circuit activates and output voltage drops. Because of this drop, the foldback circuit activates too, and output voltage drops further decreasing output current. When the output pin is shorted, a current of about 80 mA flows.

CE Pin

The CE pin allows shutdown internal circuitry to minimize power consumption. In shutdown mode, output at the V_{OUT} pin is pulled down to the V_{SS} level by R_{DCH} resistor and N-channel switch, as well as resistors R1 and R2 connected in series.

Note that the IXD1504 CE input is active HIGH and has no pull down resistor. IC will be in unstable state, if CE pin is open. CE pin current consumption may increase, if voltage applied to this pin is ~ 0.5 of V_{IN} .

C_L High-speed Discharge Function

The N-channel transistor located between V_{OUT} and V_{SS} pins quickly discharge the output capacitor (C_L), when the CE pin does low. The discharge time of the output capacitor (C_L) is set by the C_L auto-discharge resistance $R_{DCH} = 450 \Omega$ (TYP.) and the output capacitance (C_L).

Time constant $\tau = C_L \times R_{DCH}$ determines the output voltage after discharge as

$$V = V_{OUT(E)} \times e^{-t/\tau}$$

where: $V_{OUT(E)}$ - Output voltage, and t - Discharge time

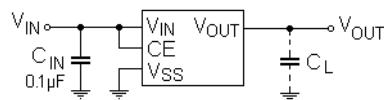
Discharge time can be calculated also by the next formula:

$$t = \tau \times \ln(V_{OUT(E)}/V)$$

Low ESR Capacitors

An internal phase compensation circuit guarantees stable IXD1504 operation without output capacitor, or with low ESR capacitors. However, connect the output capacitor C_L as close to the V_{OUT} and the V_{SS} pins as possible, if it is used. In addition, an input capacitor $C_{IN} \geq 0.1\mu F$ between the V_{IN} and V_{SS} pins should be used to ensure a stable input power.

TYPICAL APPLICATION CIRCUIT

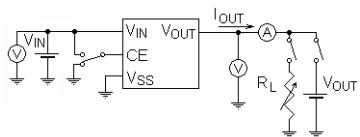


LAYOUT AND USE CONSIDERATIONS

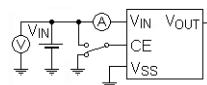
1. Mount external component as close to the IC as possible and use thick, short connecting traces to reduce the circuit impedance.
2. The IC may malfunction if absolute maximum ratings are exceeded.
3. If power source of this regulator is a high impedance device, an input capacitor $C_{IN} \geq 0.1\mu F$ should be used to prevent oscillations.
4. In case of high output current, increasing the input capacitor value can stabilize operations.
5. Please ensure that output current I_{OUT} is less than $P_D / (V_{IN} - V_{OUT})$, where P_D is a rated power dissipation value of the package shown at ABSOLUTE MAXIMUM RATING table to not exceed it.

TEST CIRCUITS

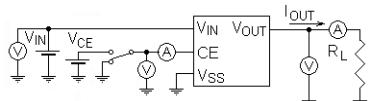
Circuit ①



Circuit ②



Circuit ③

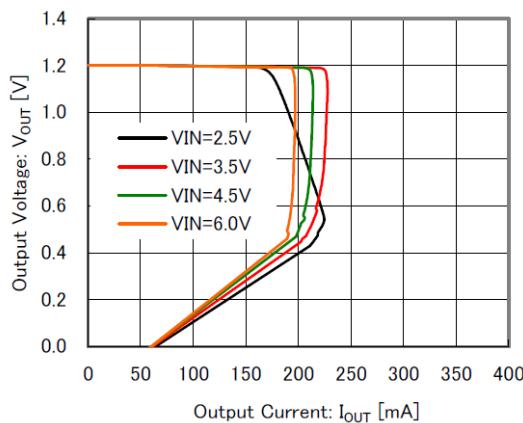


Unless otherwise stated, $T_a = 25^\circ\text{C}$, $V_{CE} = V_{IN}$, $I_{OUT} = 1 \text{ mA}$, $C_{IN} = C_L = \text{open}$, $V_{IN} = 3.5 \text{ V}$, if $V_{OUT(T)} < 2.5 \text{ V}$, or $V_{IN} = V_{OUT(T)} + 1.0 \text{ V}$

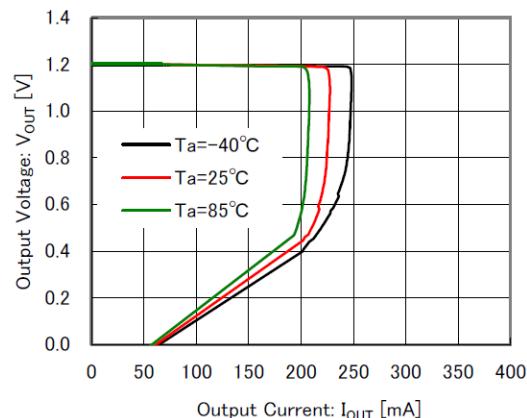
TYPICAL PERFORMANCE CHARACTERISTICS

(1) Output Voltage vs. Output Current

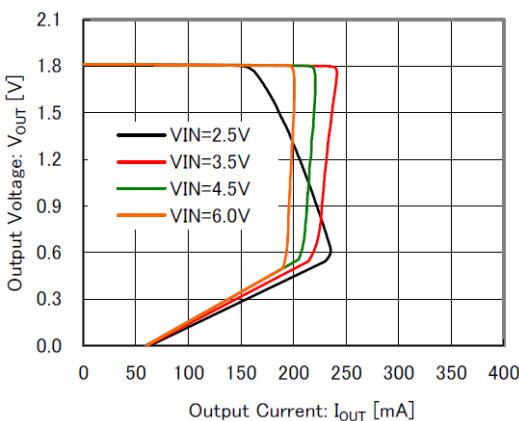
IXD1504A121xR



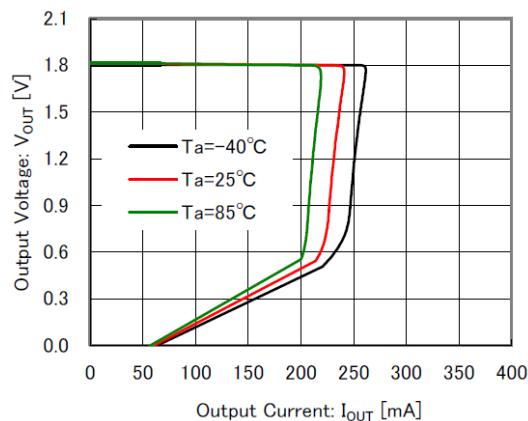
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IXD1504A181xR



IXD1504A181xR



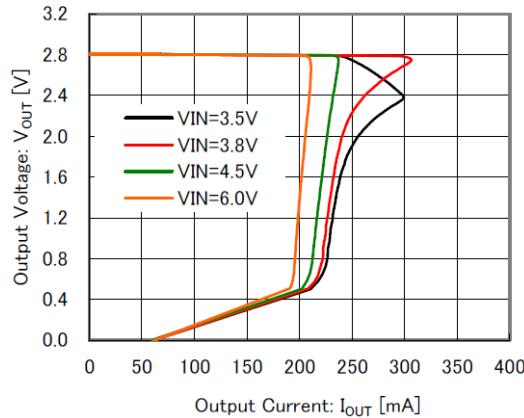
IXD1504

IXYS POWER ICs

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

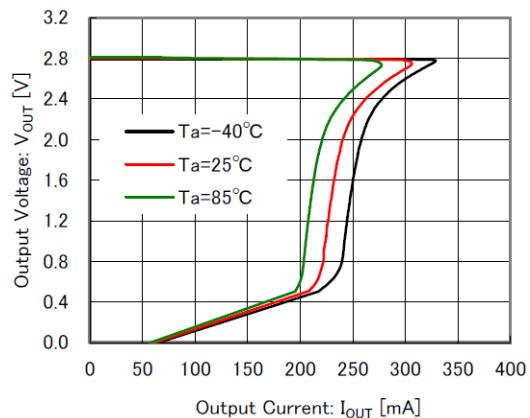
(1) Output Voltage vs Output Current (Continue)

IXD1504A281xR

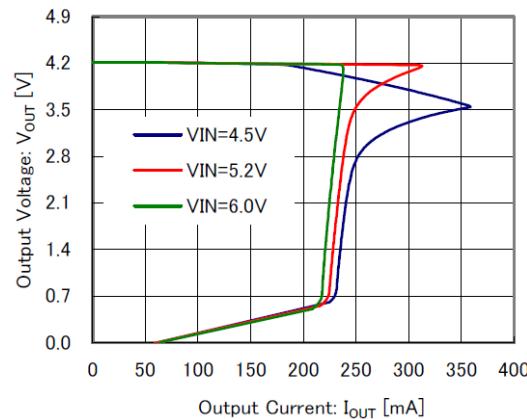


Topr = 25 °C

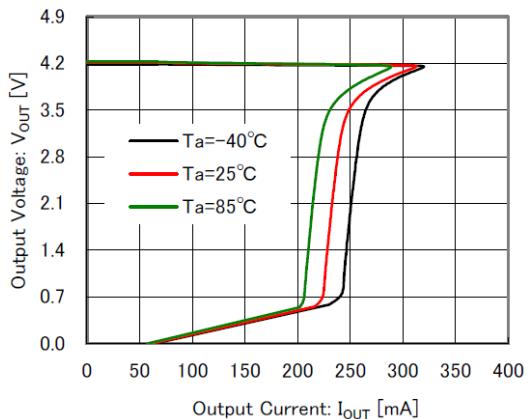
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IXD1504A421xR

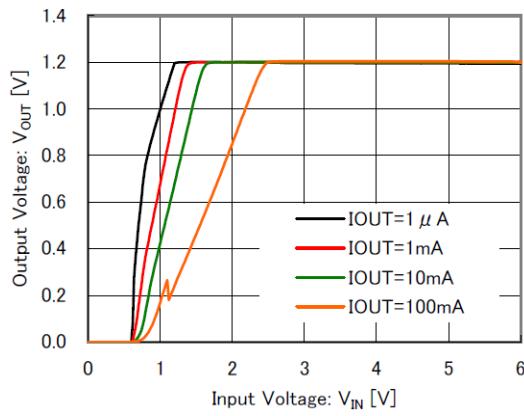


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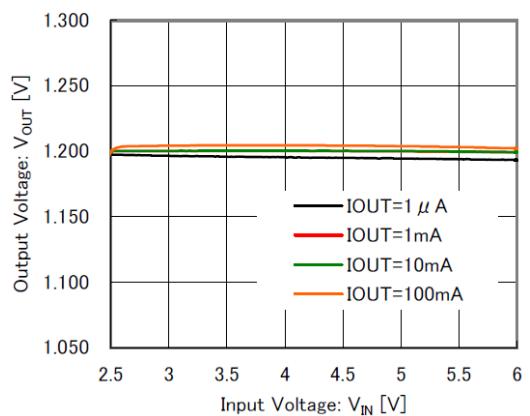


(2) Output Voltage vs. Input Voltage

IXD1504A121xR



IXD1504A121xR

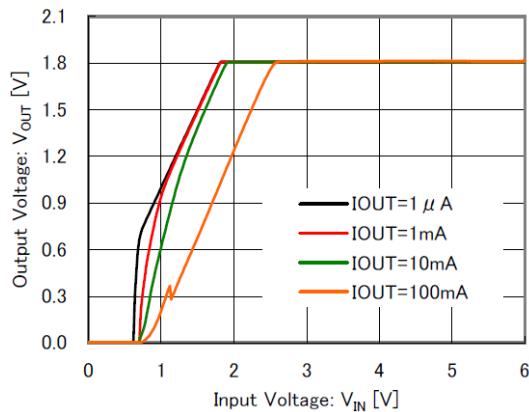


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

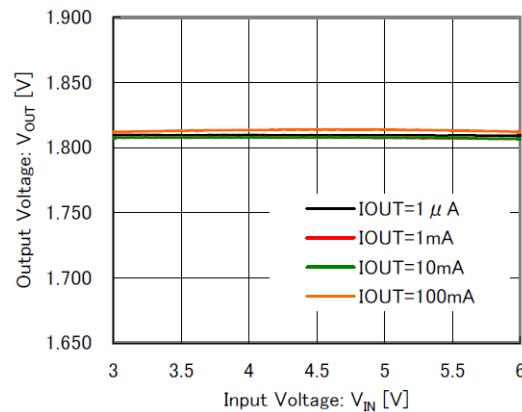
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$T_{OPR} = 25^{\circ}\text{C}$

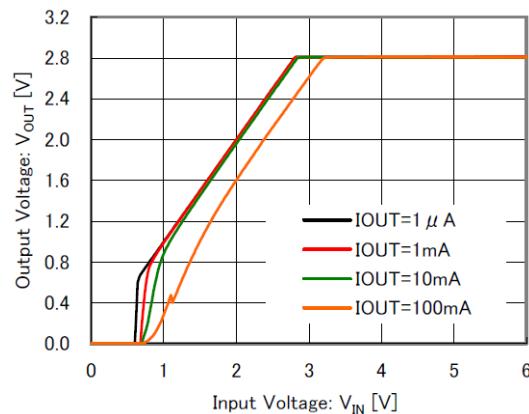
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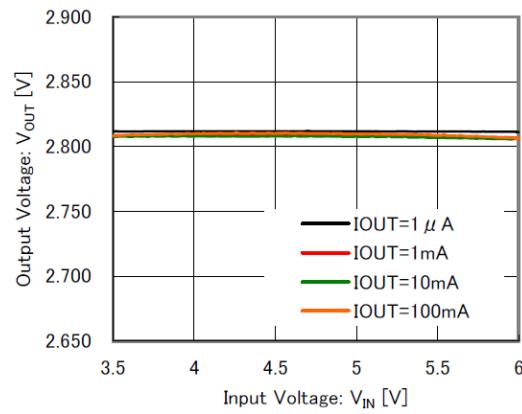
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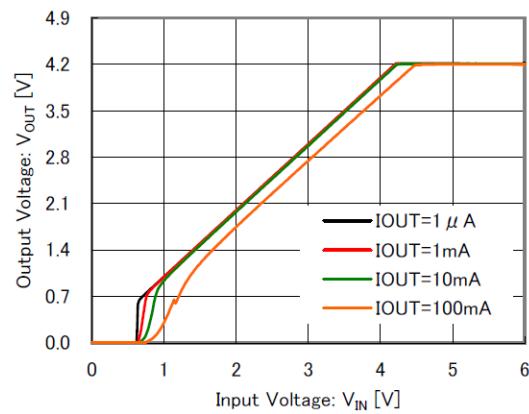
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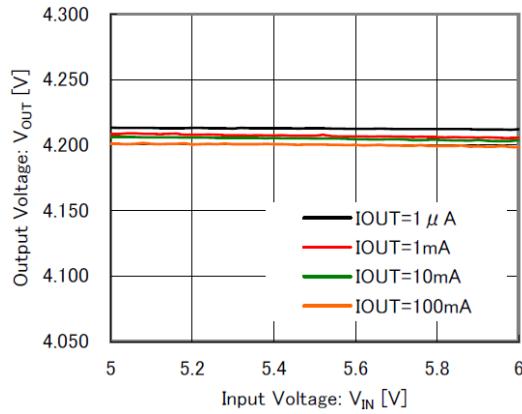
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IXD1504A421xR



IXD1504A421xR



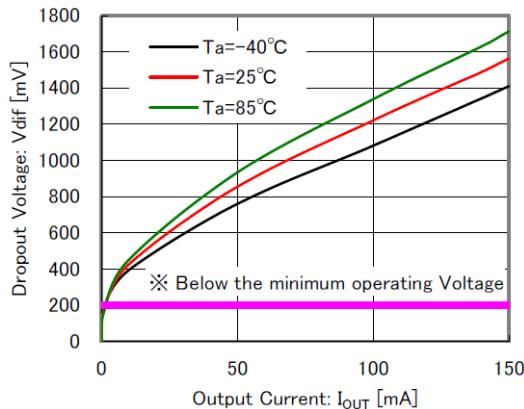
IXD1504

IXYS POWER ICs

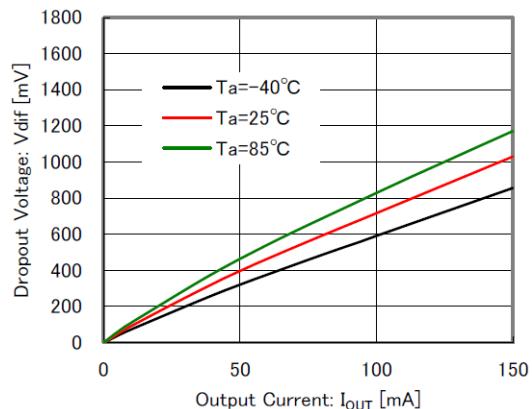
TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(3) Dropout Voltage vs. Output Current

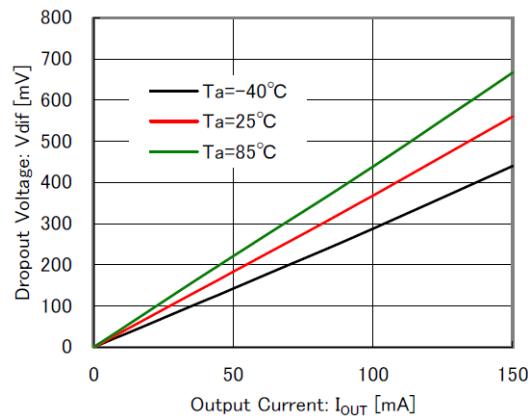
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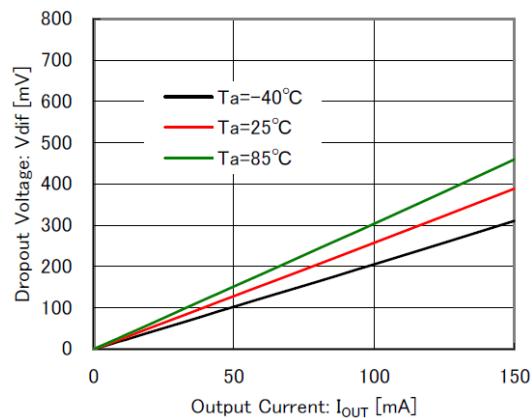
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IXD1504A281xR



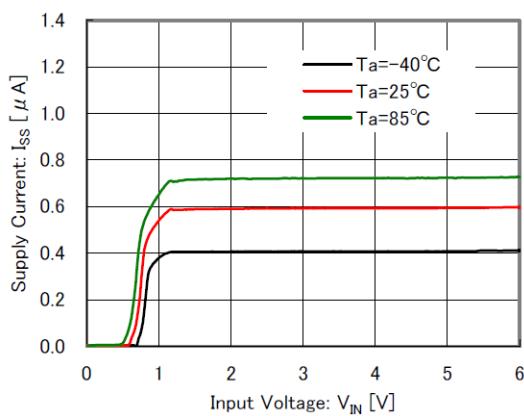
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(4) Supply Current vs. Input Voltage

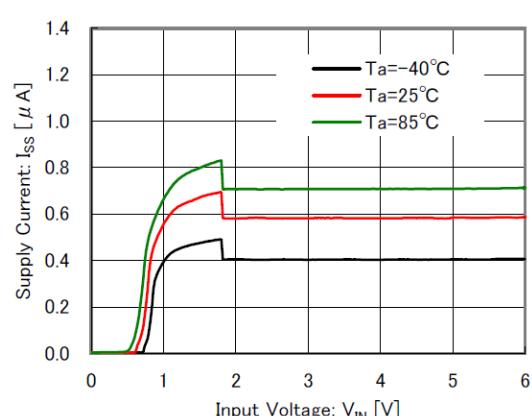
IXD1504A121xR

$I_{out} = 0 \text{ mA}$



IXD1504A181xR

$I_{out} = 0 \text{ mA}$

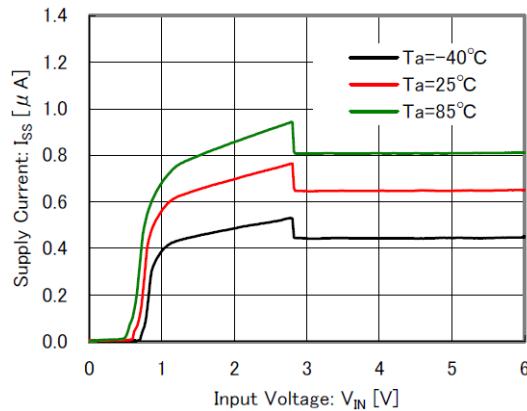


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(4) Supply Current vs. Input Voltage (Continue)

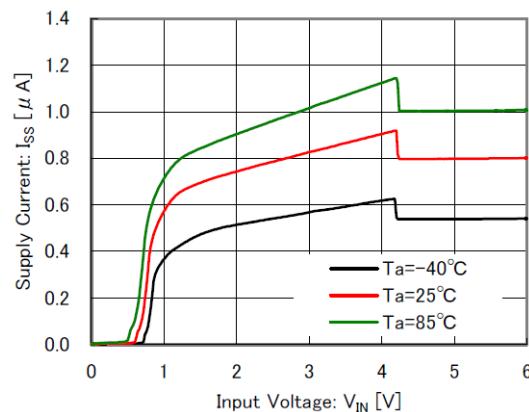
IXD1504A281xR

$I_{OUT} = 0 \text{ mA}$



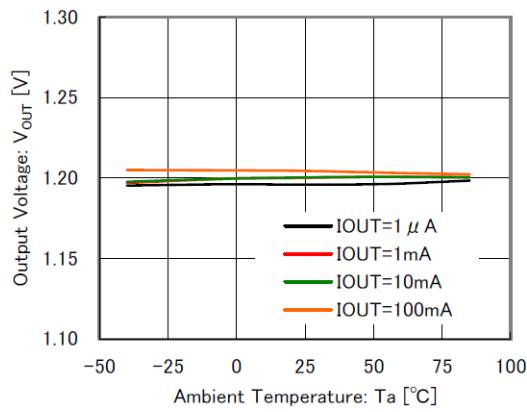
IXD1504A421xR

$I_{OUT} = 0 \text{ mA}$

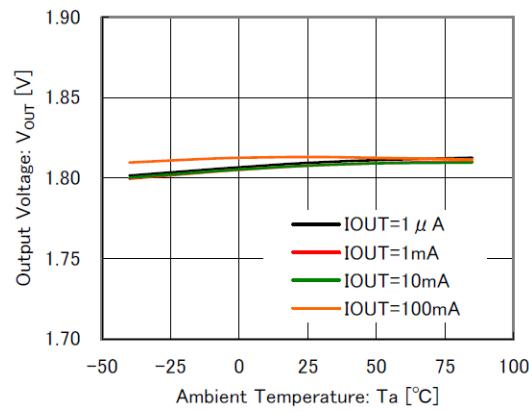


(5) Output Voltage vs. Ambient temperature

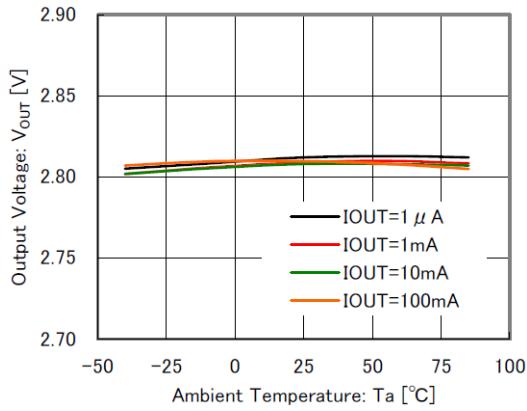
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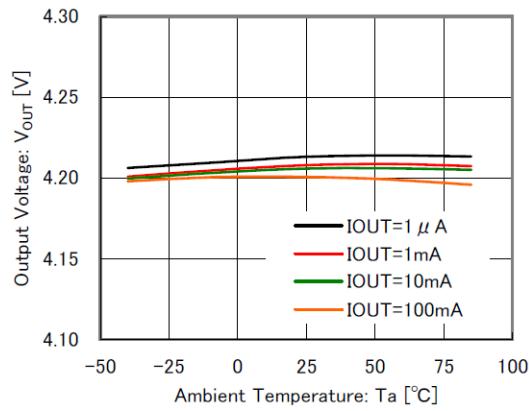
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IXD1504A281xR



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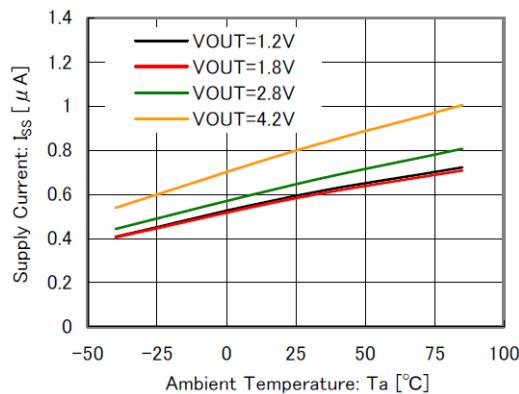


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(6) Supply Current vs. Ambient Temperature

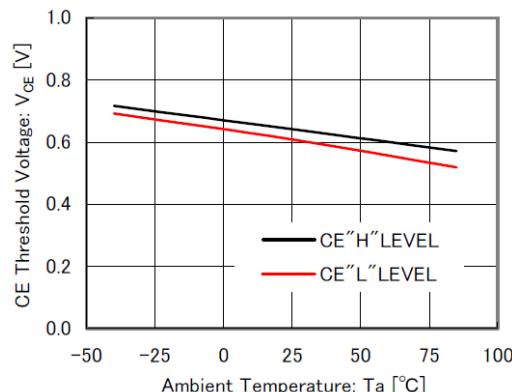
IXD1504Axx1xR

$I_{OUT} = 0 \text{ mA}$



(7) CE Threshold Voltage vs. Ambient Temperature

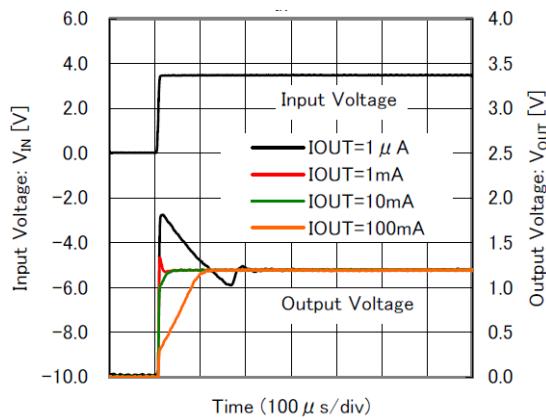
IXD1504Axx1xR



(8) Input Voltage Rising Response Time

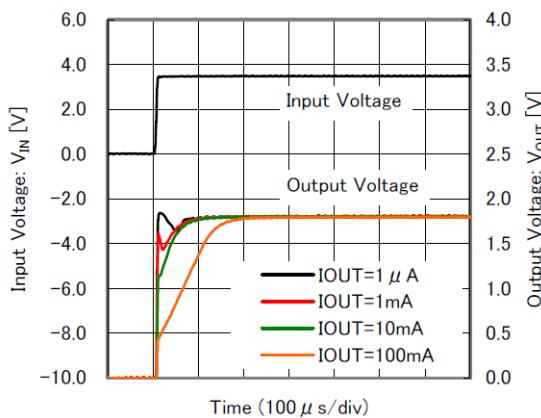
IXD1504A121xR

$V_{IN} = 0 \text{ V} \rightarrow 3.5 \text{ V}, t_R = 5 \mu\text{s}$



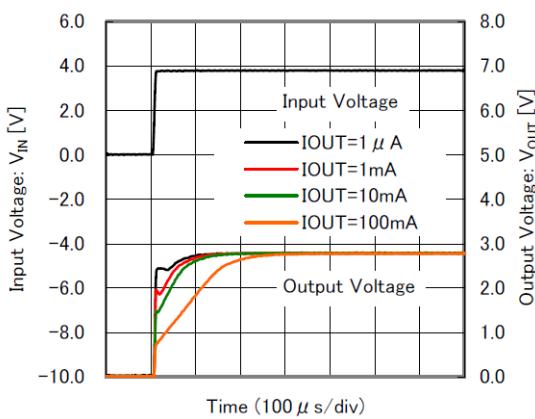
IXD1504A181xR

$V_{IN} = 0 \text{ V} \rightarrow 3.5 \text{ V}, t_R = 5 \mu\text{s}$



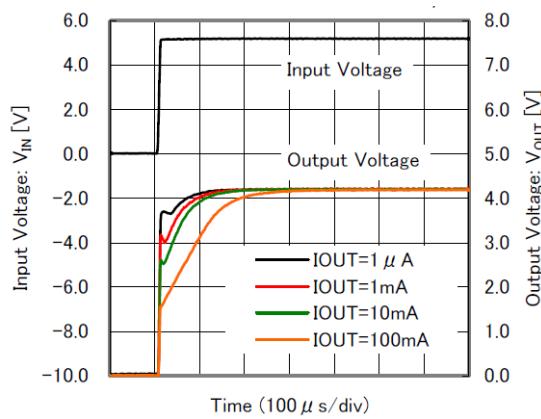
IXD1504A281xR

$V_{IN} = 0 \text{ V} \rightarrow 3.8 \text{ V}, t_R = 5 \mu\text{s}$



IXD1504A421xR

$V_{IN} = 0 \text{ V} \rightarrow 5.2 \text{ V}, t_R = 5 \mu\text{s}$

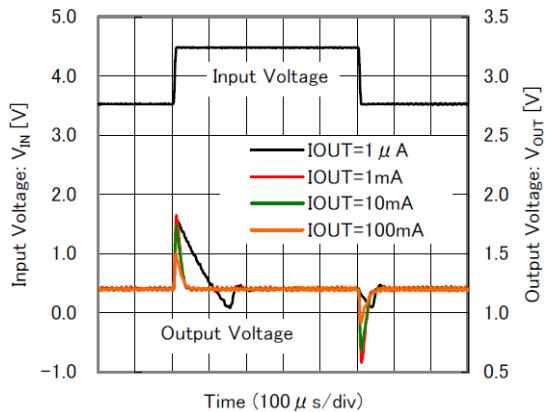


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(9) Input Voltage Transient Response

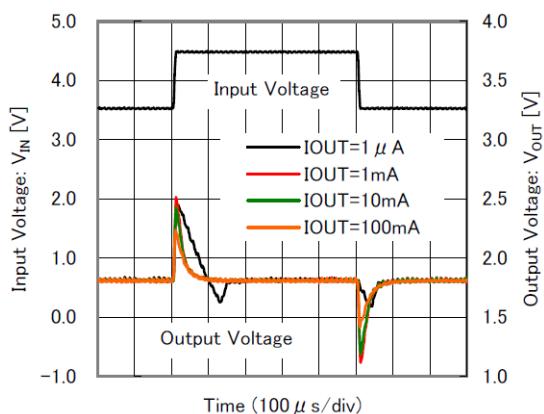
IXD1504A121xR

$V_{IN} = 3.5 \text{ V} \leftrightarrow 4.5 \text{ V}$, $t_R = t_F = 5 \mu\text{s}$



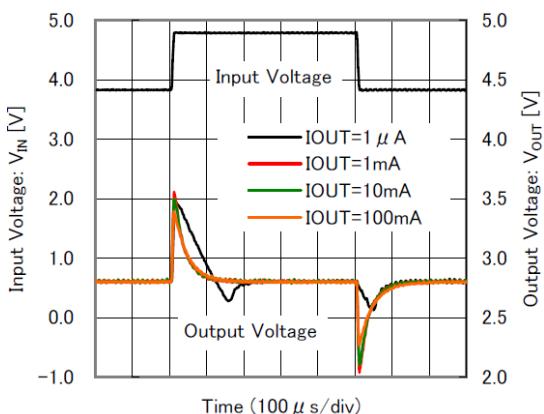
IXD1504A181xR

$V_{IN} = 3.5 \text{ V} \leftrightarrow 4.5 \text{ V}$, $t_R = t_F = 5 \mu\text{s}$



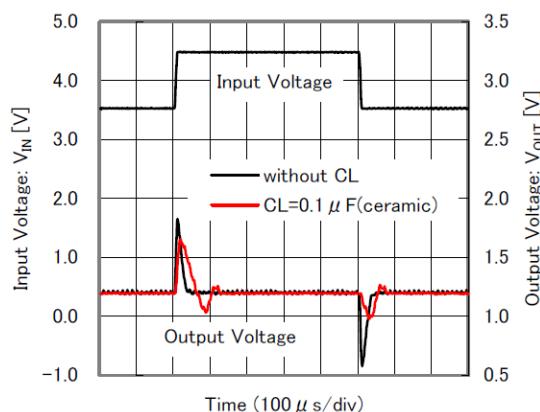
IXD1504A281xR

$V_{IN} = 3.8 \text{ V} \leftrightarrow 4.8 \text{ V}$, $t_R = t_F = 5 \mu\text{s}$



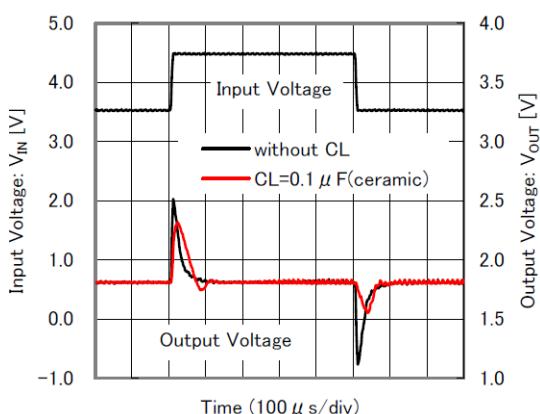
IXD1504A121xR

$V_{IN} = 3.5 \text{ V} \leftrightarrow 4.5 \text{ V}$, $t_R = t_F = 5 \mu\text{s}$



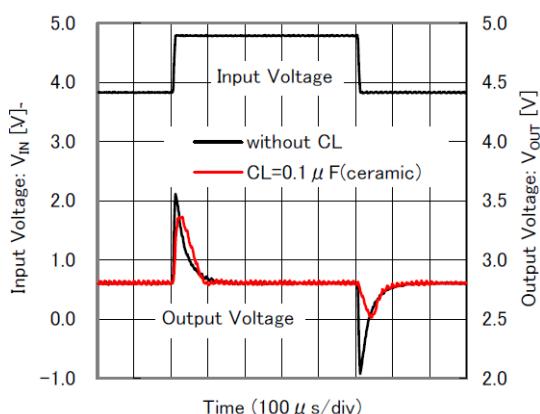
IXD1504A181xR

$V_{IN} = 3.5 \text{ V} \leftrightarrow 4.5 \text{ V}$, $t_R = t_F = 5 \mu\text{s}$



IXD1504A281xR

$V_{IN} = 3.8 \text{ V} \leftrightarrow 4.8 \text{ V}$, $t_R = t_F = 5 \mu\text{s}$

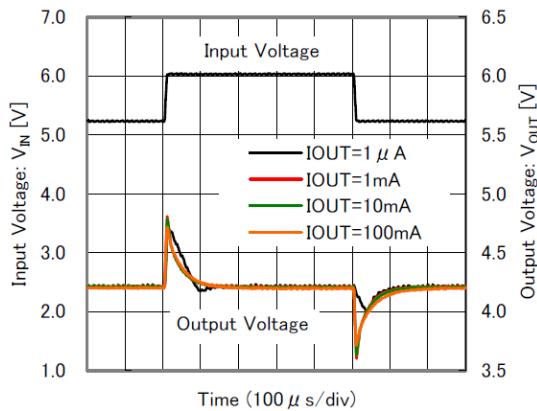


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(9) Input Voltage Transient Response (Continued)

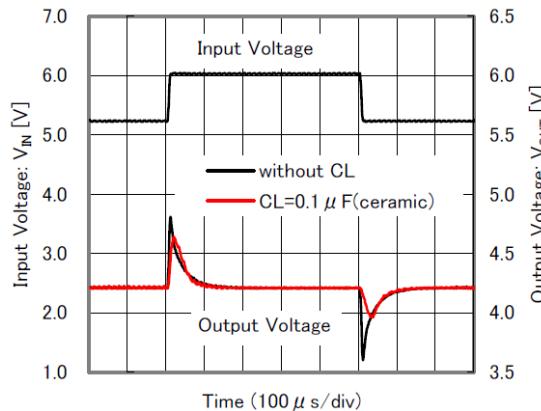
IXD1504A421xR

$V_{IN} = 5.2 \text{ V} \rightarrow 6.0 \text{ V}$, $t_R = t_F = 5 \mu\text{s}$



IXD1504A421xR

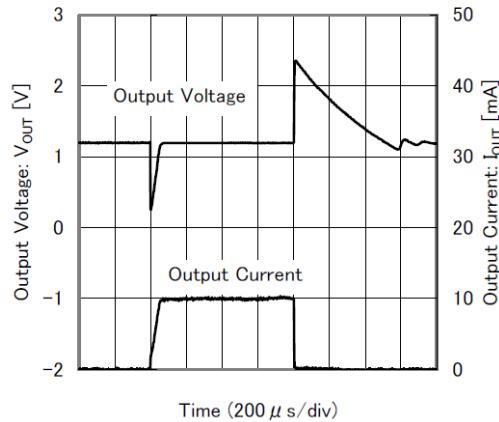
$V_{IN} = 5.2 \text{ V} \rightarrow 6.0 \text{ V}$, $t_R = t_F = 5 \mu\text{s}$



(10) Load Transient Response

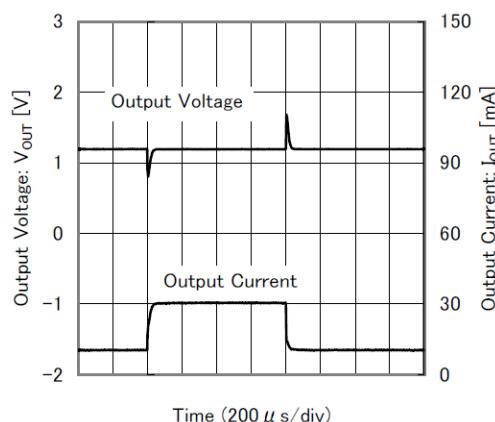
IXD1504A121xR

$I_{OUT} = 1 \mu\text{A} \leftrightarrow 10 \text{ mA}$, $t_R = t_F = 5 \mu\text{s}$



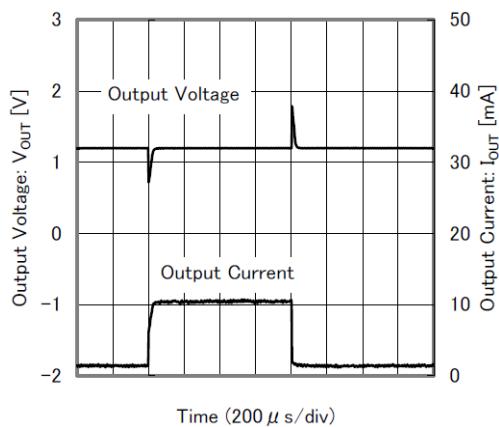
IXD1504A121xR

$I_{OUT} = 10 \text{ mA} \leftrightarrow 30 \text{ mA}$, $t_R = t_F = 5 \mu\text{s}$



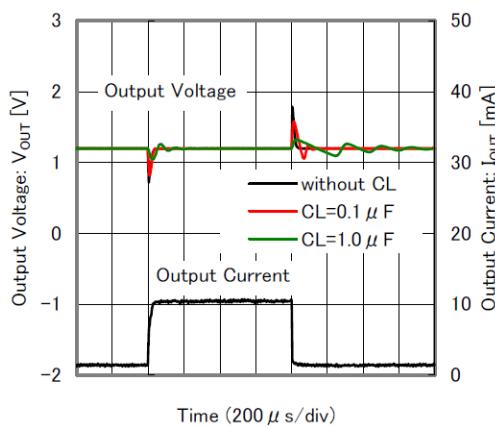
IXD1504A121xR

$I_{OUT} = 1 \text{ mA} \leftrightarrow 10 \text{ mA}$, $t_R = t_F = 5 \mu\text{s}$



IXD1504A121xR

$I_{OUT} = 1 \text{ mA} \leftrightarrow 10 \text{ mA}$, $t_R = t_F = 5 \mu\text{s}$

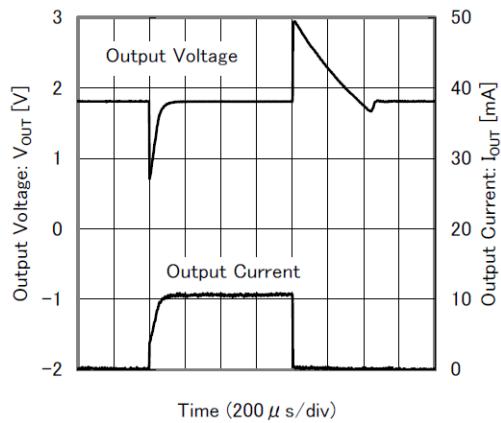


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(10) Load Transient Response (Continue)

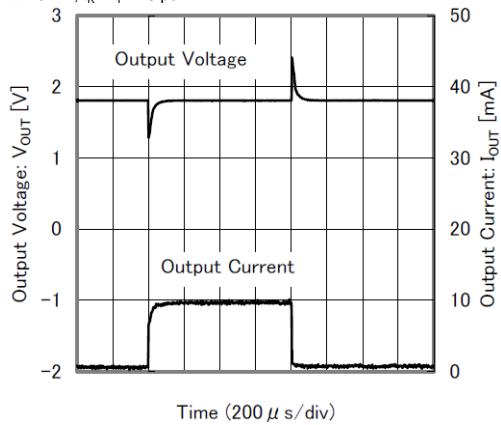
IXD1504A181xR

$I_{OUT} = 1 \mu A \leftrightarrow 10 mA, t_R = t_F = 5 \mu s$



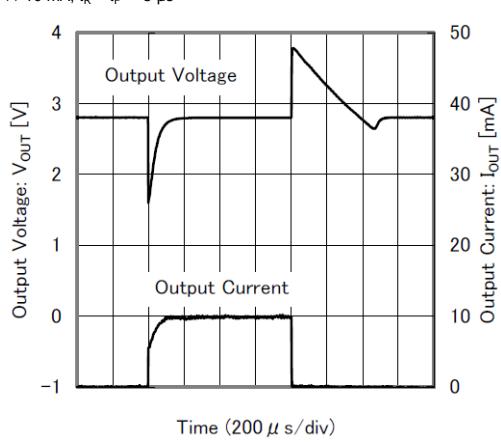
IXD1504A181xR

$I_{OUT} = 1 mA \leftrightarrow 10 mA, t_R = t_F = 5 \mu s$



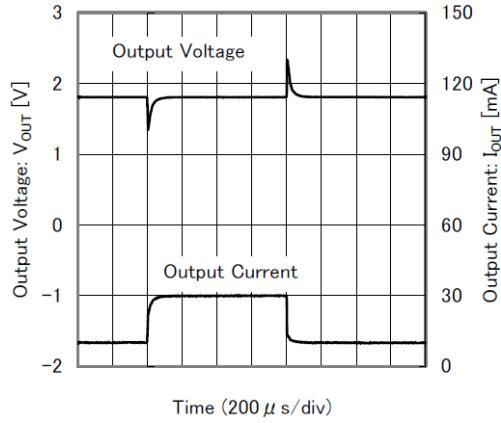
IXD1504A281xR

$I_{OUT} = 1 \mu A \leftrightarrow 10 mA, t_R = t_F = 5 \mu s$



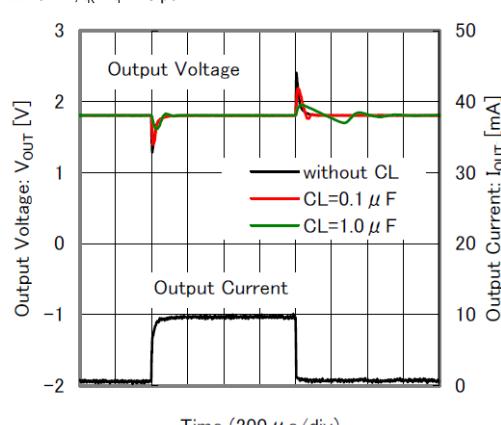
IXD1504A181xR

$I_{OUT} = 10 mA \leftrightarrow 30 mA, t_R = t_F = 5 \mu s$



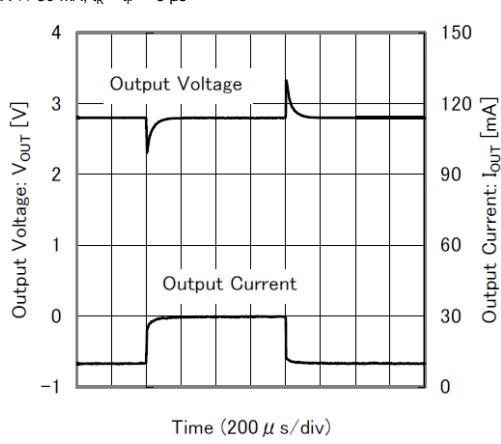
IXD1504A181xR

$I_{OUT} = 1 mA \leftrightarrow 10 mA, t_R = t_F = 5 \mu s$



IXD1504A281xR

$I_{OUT} = 10 mA \leftrightarrow 30 mA, t_R = t_F = 5 \mu s$



IXD1504

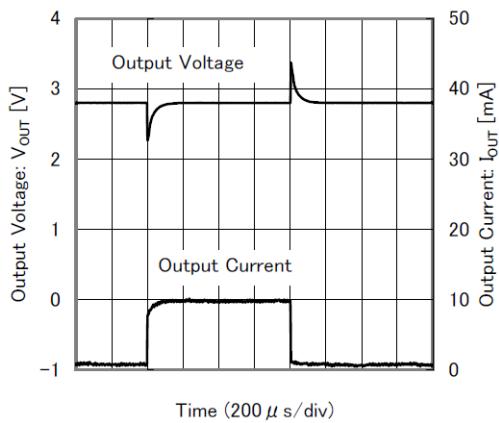
IXYS POWER ICs

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(10) Load Transient Response (Continue)

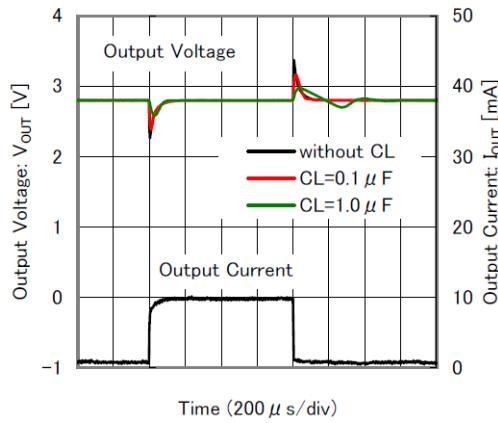
IXD1504A281xR

$I_{OUT} = 1 \text{ mA} \leftrightarrow 10 \text{ mA}$, $t_R = t_F = 5 \mu\text{s}$



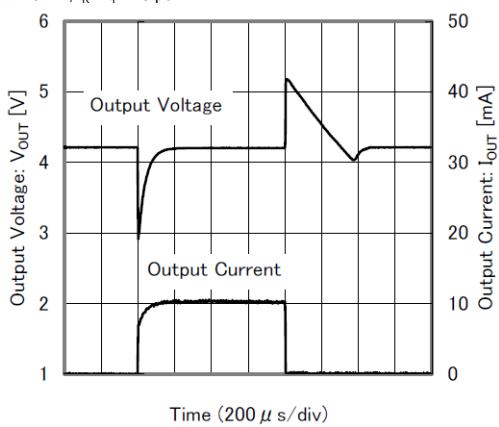
IXD1504A281xR

$I_{OUT} = 1 \text{ mA} \leftrightarrow 10 \text{ mA}$, $t_R = t_F = 5 \mu\text{s}$



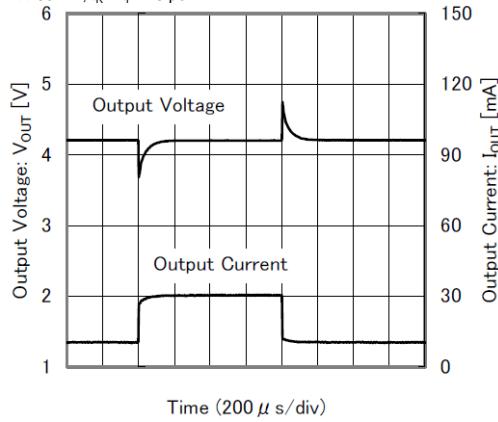
IXD1504A421xR

$I_{OUT} = 1 \mu\text{A} \leftrightarrow 10 \text{ mA}$, $t_R = t_F = 5 \mu\text{s}$



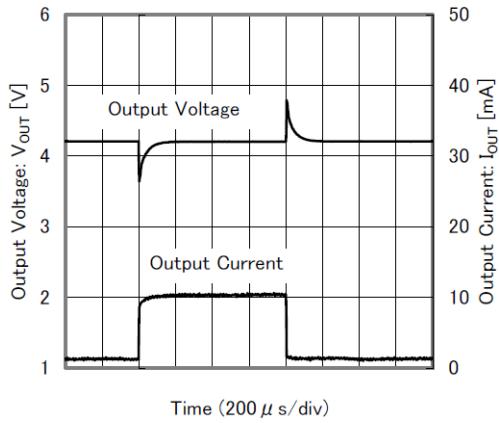
IXD1504A421xR

$I_{OUT} = 10 \text{ mA} \leftrightarrow 30 \text{ mA}$, $t_R = t_F = 5 \mu\text{s}$



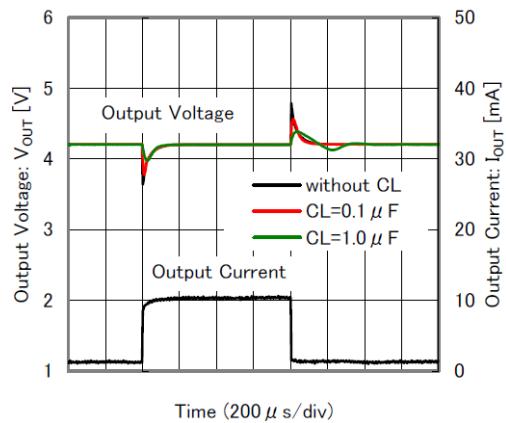
IXD1504A421xR

$I_{OUT} = 1 \text{ mA} \leftrightarrow 10 \text{ mA}$, $t_R = t_F = 5 \mu\text{s}$



IXD1504A421xR

$I_{OUT} = 1 \text{ mA} \leftrightarrow 10 \text{ mA}$, $t_R = t_F = 5 \mu\text{s}$

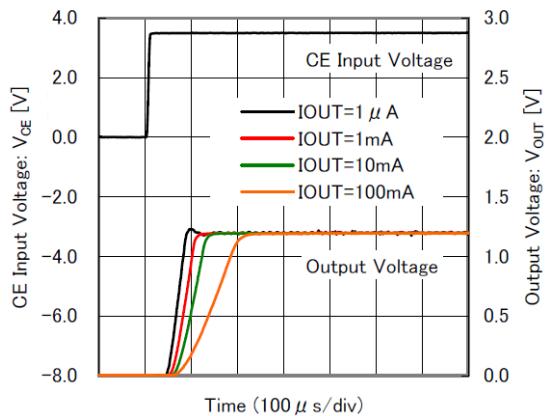


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(11) CE Voltage Rising Response Time

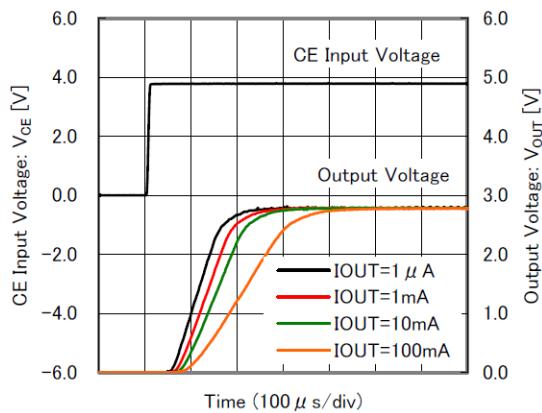
IXD1504A121xR

V_{CE} = 0 V → V_{IN}, t_R = 5 μs



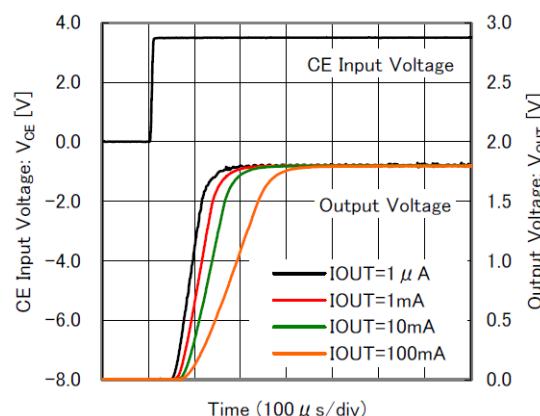
IXD1504A281xR

V_{CE} = 0 V → V_{IN}, t_R = 5 μs



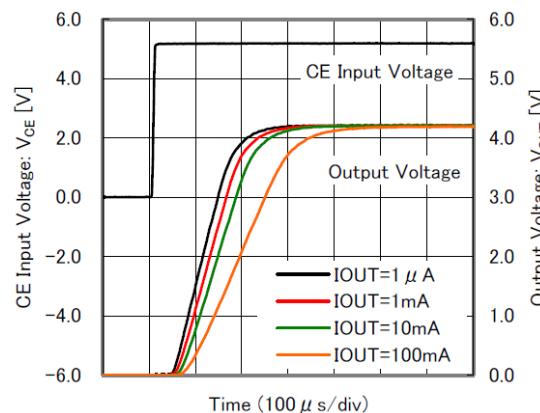
IXD1504A181xR

V_{CE} = 0 V → V_{IN}, t_R = 5 μs



IXD1504A421xR

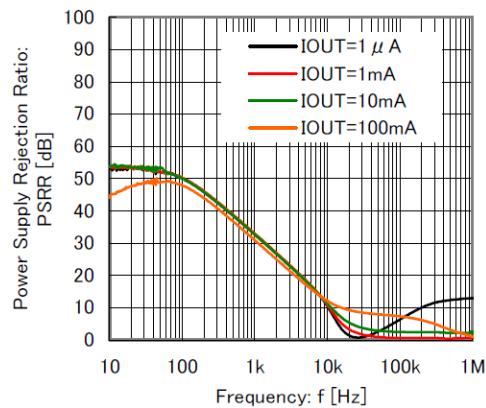
V_{CE} = 0 V → V_{IN}, t_R = 5 μs



(12) Power Supply Rejection Ratio

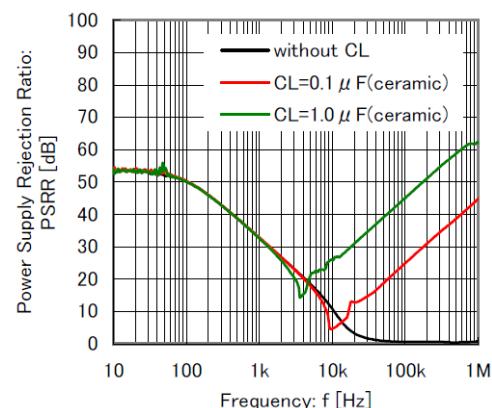
IXD1504A121xR

V_{IN} = 3.5 V + 0.5 V_{p-pAC}



IXD1504A121xR

V_{IN} = 3.5 V + 0.5 V_{p-pAC}



IXD1504

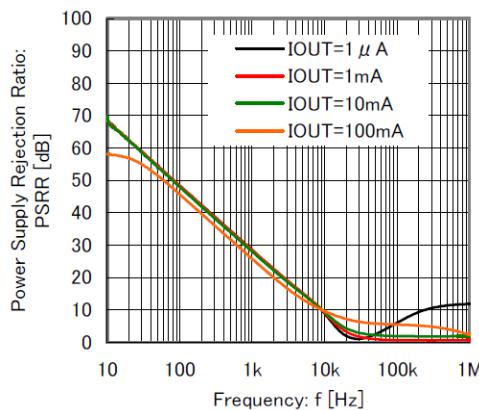
IXYS POWER ICs

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(12) Power Supply Rejection Ratio (Continue)

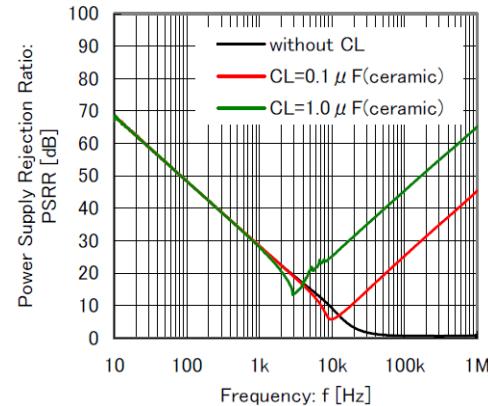
IXD1504A181xR

$V_{IN} = 3.5 \text{ V} + 0.5 \text{ V}_{p-p_{AC}}$



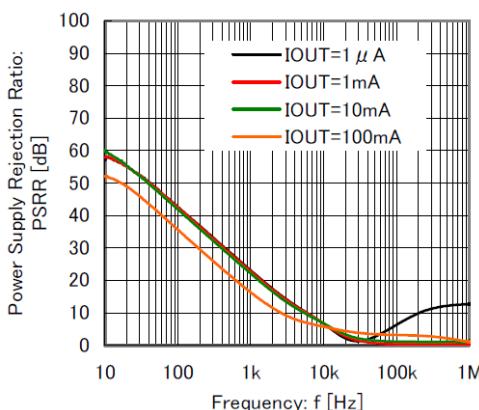
IXD1504A181xR

$V_{IN} = 3.5 \text{ V} + 0.5 \text{ V}_{p-p_{AC}}$



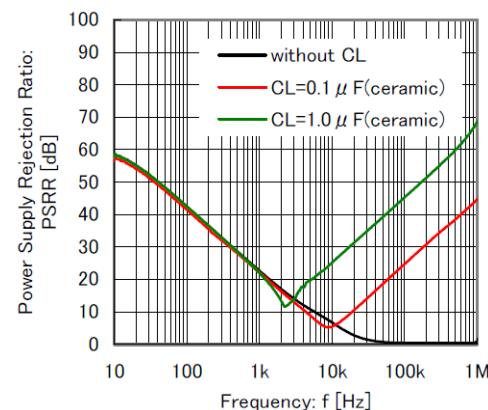
IXD1504A281xR

$V_{IN} = 3.8 \text{ V} + 0.5 \text{ V}_{p-p_{AC}}$



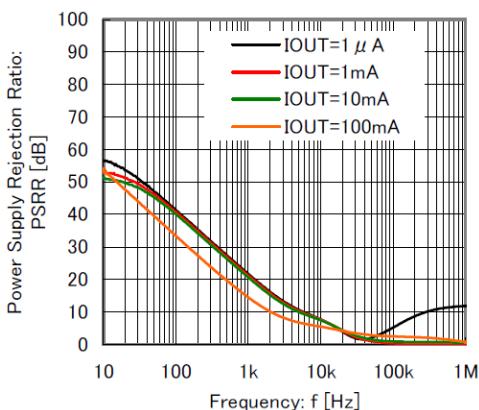
IXD1504A281xR

$V_{IN} = 3.8 \text{ V} + 0.5 \text{ V}_{p-p_{AC}}$



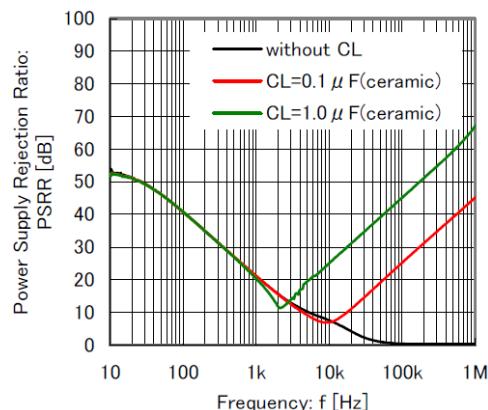
IXD1504A421xR

$V_{IN} = 5.2 \text{ V} + 0.5 \text{ V}_{p-p_{AC}}$



IXD1504A421xR

$V_{IN} = 5.2 \text{ V} + 0.5 \text{ V}_{p-p_{AC}}$



ORDERING INFORMATION

IXD1504①②③④⑤⑥-⑦

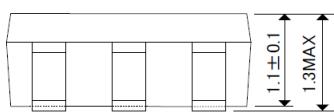
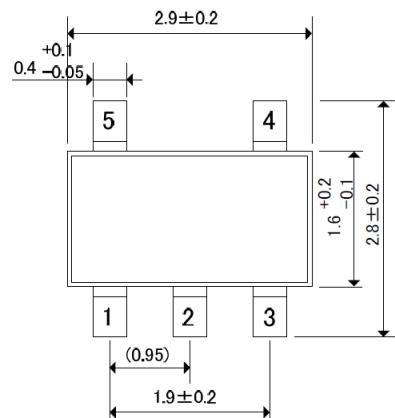
DESIGNATOR	DESCRIPTION	SYMBOL	DESCRIPTION
①	Type of Regulator	A	Current Limiter, C_L Auto Discharge, No CE Pull-down,
②③	Output Voltage ¹⁾	11 - 50	Output Voltage Range: 1.1 V ~ 5.0 V, e.g. 2.6 V - ② = 2, ③ = 6
④	Output Voltage Accuracy	1	0.10 V increments, Accuracy: $\pm 1\%$, ($V_{OUT} \geq 2$ V) or ± 0.02 V ($V_{OUT} < 2$ V),
⑤⑥-⑦ ^(*)	Packages (Order Limit)	MR-G	SOT-25 (3000/Reel)
		NR-G	SSOT-24 (3000/Reel)
		7R-G	USPN-4802 (5000/Reel)

NOTE:

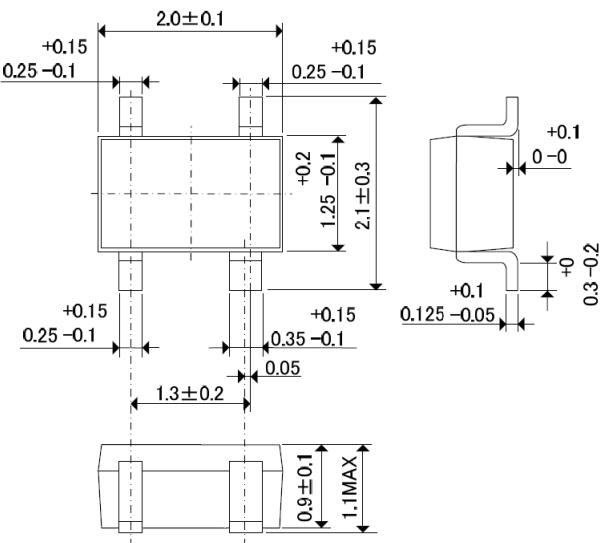
The “-G” suffix denotes Halogen and Antimony free as well as being fully RoHS compliant.

PACKAGE DRAWING AND DIMENSIONS

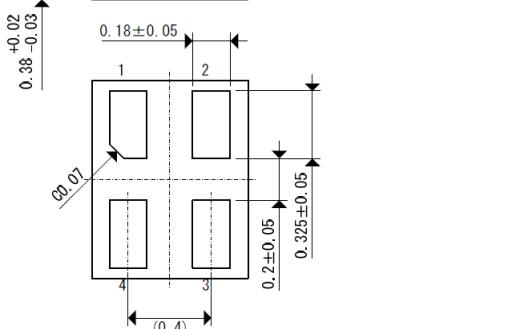
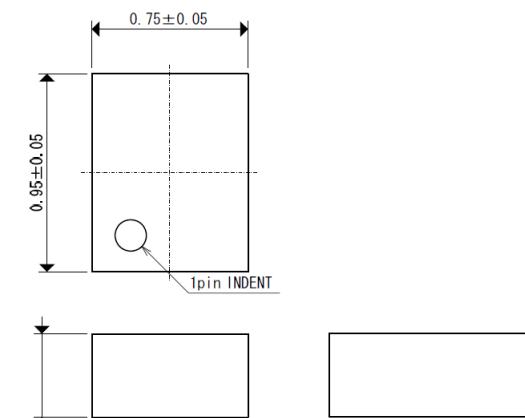
SOT-25, Units: mm



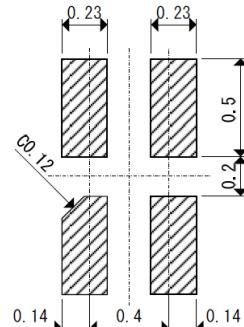
SSOT-24 Units: mm



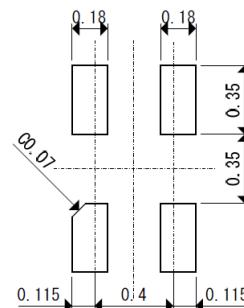
USPN-4B02, Units: mm



USPN-4B02 Reference Pattern Layout, Units: mm



USPN-4B02 Reference Metal Mask Design, Units: mm



PACKAGE POWER DISSIPATION**SOT-25 Power Dissipation**

The power dissipation varies with the mount board conditions.
Please use this data as a reference only.

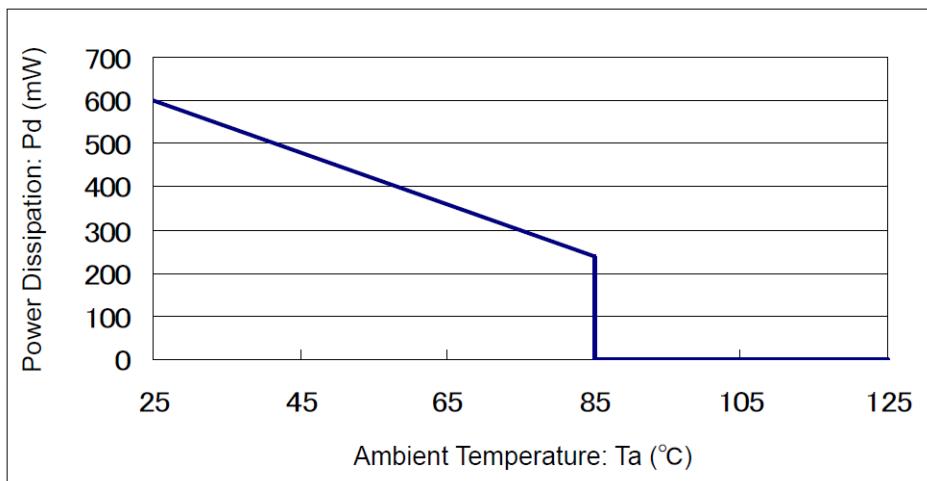
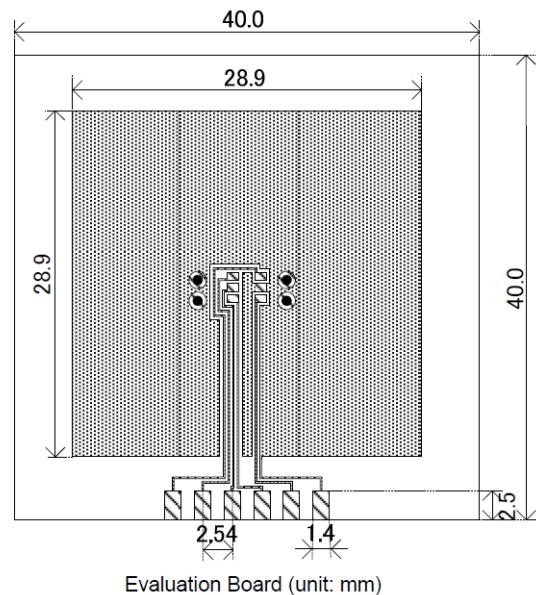
1. Measurement Conditions:

Condition: Mount on a board
 Ambient: Natural convection
 Soldering: Lead (Pb) free
 Board: Dimensions 40x40 mm (1600 mm² in one side)
 Copper (Cu) traces occupy 50% of the board area
 on top and bottom layers
 Package heat sink tied to the copper traces.
 (Board of SOT-26 is used)
 Material: Glass Epoxy (FR-4)
 Thickness: 1.6 mm
 Through-hole: 4 x 0.8 Diameter

2. Power Dissipation vs. Ambient Temperature

Board Mount ($T_{jmax} = 125^{\circ}\text{C}$)

Ambient Temperature, $^{\circ}\text{C}$	Power Dissipation P_d , mW	Thermal Resistance, $^{\circ}\text{C}/\text{W}$
25	600	166.67
85	240	



PACKAGE POWER DISSIPATION (CONTINUED)

SSOT-24 Power Dissipation

The power dissipation varies with the mount board conditions.
Please use this data as a reference only.

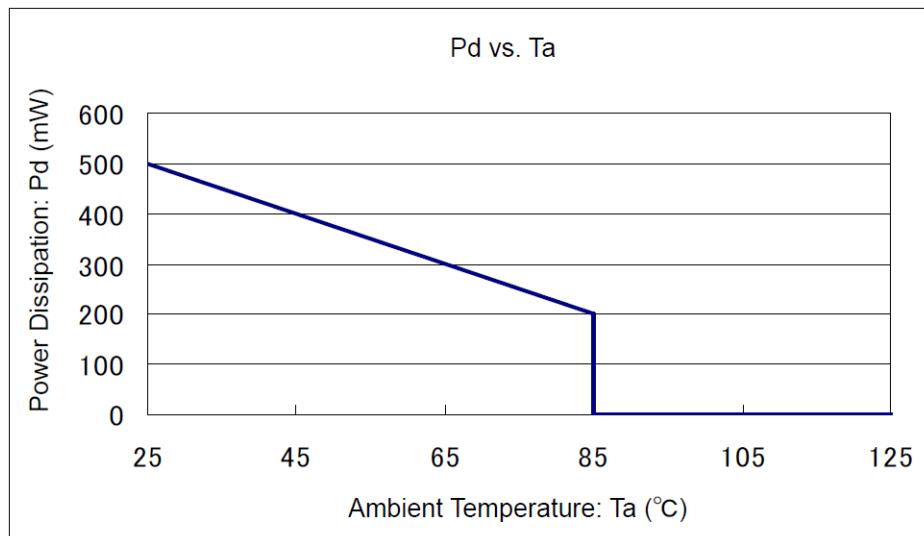
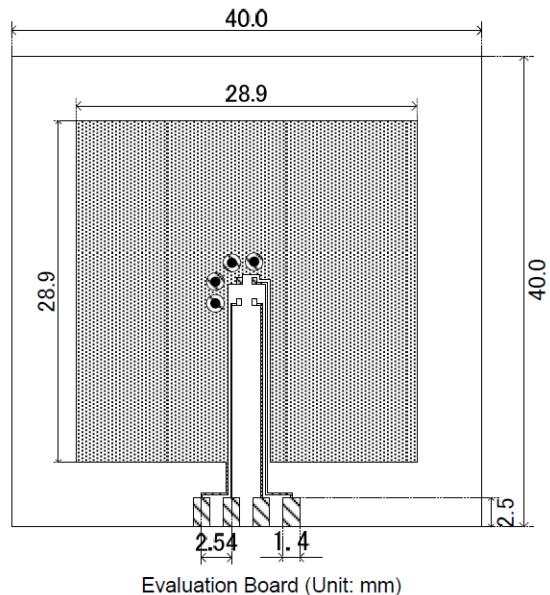
1. Measurement Conditions:

Condition: Mount on a board
 Ambient: Natural convection
 Soldering: Lead (Pb) free
 Board: Dimensions 40x40 mm (1600 mm² in one side)
 Copper (Cu) traces occupy 50% of the board area
 on top and bottom layers
 Package heat sink tied to the copper traces.
 (Board of SOT-26 is used)
 Material: Glass Epoxy (FR-4)
 Thickness: 1.6 mm
 Through-hole: 4 x 0.8 Diameter

2. Power Dissipation vs. Ambient Temperature

Board Mount (T_{jmax} = 125 °C)

Ambient Temperature, °C	Power Dissipation Pd, mW	Thermal Resistance, °C/W
25	500	200.00
85	200	



PACKAGE POWER DISSIPATION (CONTINUED)

USPN-4B02 Power Dissipation

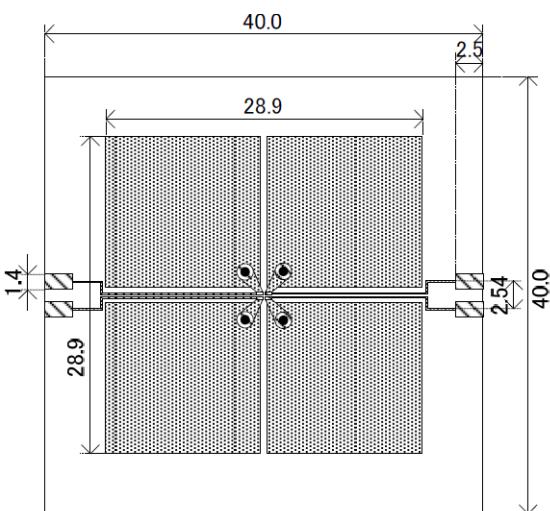
The power dissipation varies with the mount board conditions.
Please use this data as a reference only.

1. Measurement Conditions:

Condition: Mount on a board
 Ambient: Natural convection
 Soldering: Lead (Pb) free
 Board: Dimensions 40x40 mm (1600 mm² in one side)
 Copper (Cu) traces occupy 50% of the board area
 on top and bottom layers
 The copper area is divided into four identical blocks
 of 12.5% each.
 Each terminal of USPN-4B02 package connected to
 one of the blocks.
 Material: Glass Epoxy (FR-4)
 Thickness: 1.6 mm
 Through-hole: 4 x 0.8 Diameter

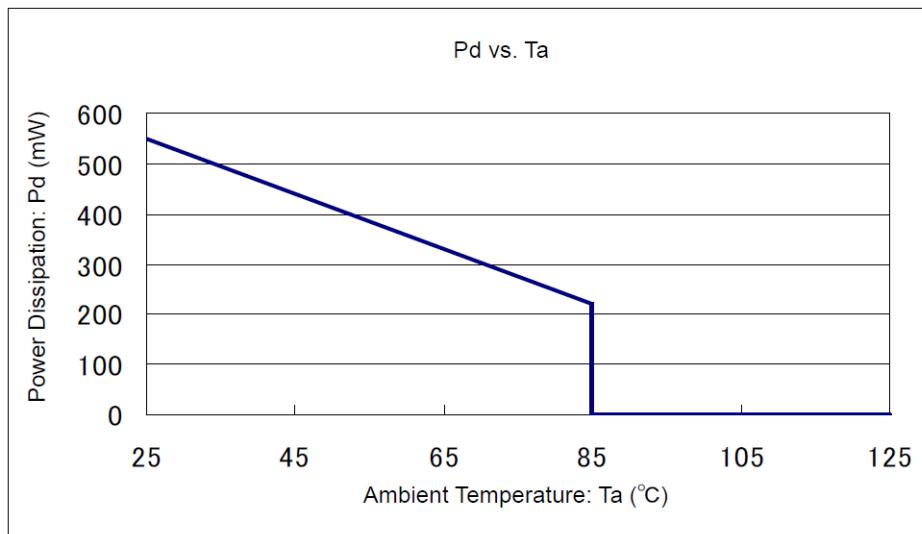
2. Power Dissipation vs. Ambient Temperature

Board Mount ($T_{jmax} = 125^{\circ}\text{C}$)



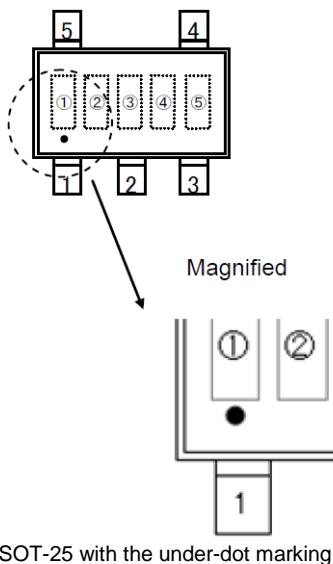
Evaluation Board (Unit: mm)

Ambient Temperature, $^{\circ}\text{C}$	Power Dissipation P_d , mW	Thermal Resistance, $^{\circ}\text{C/W}$
25	550	181.82
85	220	



MARKING

SOT-25



SOT-25 with the under-dot marking

① - represents product series

MARK	PRODUCT SERIES
9	IXD1504xxxxx-G

② - represents type of regulator

MARK		PRODUCT SERIES
V_{OUT}		
1.1 V – 3.9 V	4.0 V – 5.0 V	
K	M	IXD1504Axxxx-G

③ - represents output voltage

MARK	OUTPUT VOLTAGE, V	
0	-	4.0
1	1.1	4.1
2	1.2	4.2
3	1.3	4.3
4	1.4	4.4
5	1.5	4.5
6	1.6	4.6
7	1.7	4.7
8	1.8	4.8
9	1.9	4.9
A	2.0	5.0
B	2.1	
C	2.2	
D	2.3	
E	2.4	

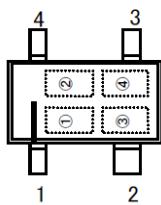
MARK	OUTPUT VOLTAGE, V	
F	2.5	
H	2.6	
K	2.7	
L	2.8	
M	2.9	
N	3.0	
P	3.1	
R	3.2	
S	3.3	
T	3.4	
U	3.5	
V	3.6	
X	3.7	
Y	3.8	
Z	3.9	

④⑤ - represents production lot number

01~09, 0A~0Z, 11~9Z, A1~A9, AA~AZ, B1~ZZ in order, (G, I, J, O, Q, W excluded)

MARKING (Continue)

SSOT-24 (With an orientation bar at the bottom)



① - represents output voltage range

MARK	OUTPUT VOLTAGE, V	PRODUCT SERIES
P	1.1 – 3.9	IXD1504A111xx-G - IXD1504A391xx-G
R	4.0 – 5.0	IXD1504A401xx-G - IXD1504A501xx-G

② - represents output voltage

MARK	OUTPUT VOLTAGE, V	
0	-	4.0
1	1.1	4.1
2	1.2	4.2
3	1.3	4.3
4	1.4	4.4
5	1.5	4.5
6	1.6	4.6
7	1.7	4.7
8	1.8	4.8
9	1.9	4.9
A	2.0	5.0
B	2.1	
C	2.2	
D	2.3	
E	2.4	

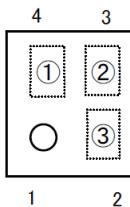
MARK	OUTPUT VOLTAGE, V	
F	2.5	
H	2.6	
K	2.7	
L	2.8	
M	2.9	
N	3.0	
P	3.1	
R	3.2	
S	3.3	
T	3.4	
U	3.5	
V	3.6	
X	3.7	
Y	3.8	
Z	3.9	

③④ - represents production lot number

01~09, 0A~0Z, 11~9Z, A1~A9, AA~AZ, B1~ZZ in order. (G, I, J, O, Q, W excluded)

MARKING

USPN-4B02



① - represents output voltage range

MARK	OUTPUT VOLTAGE, V	PRODUCT SERIES
A	1.1 – 3.9	IXD1504A111xx-G - IXD1504A391xx-G
B	4.0 – 5.0	IXD1504A401xx-G - IXD1504A501xx-G

② - represents output voltage

MARK	OUTPUT VOLTAGE, V
0	-
1	1.1
2	1.2
3	1.3
4	1.4
5	1.5
6	1.6
7	1.7
8	1.8
9	1.9
A	2.0
B	2.1
C	2.2
D	2.3
E	2.4

MARK	OUTPUT VOLTAGE, V
F	2.5
H	2.6
K	2.7
L	2.8
M	2.9
N	3.0
P	3.1
R	3.2
S	3.3
T	3.4
U	3.5
V	3.6
X	3.7
Y	3.8
Z	3.9

③ - represents production lot number

0~9, A~Z in order.
(G, I, J, O, Q, W excluded)

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IXYS Corp.
1590 Buckeye Dr.
Milpitas, CA 95035-7418
Phone: 408. 457.9000
Fax: 408. 496.0222
<http://www.ixys.com>

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